



# STGP7NC60HD STGF7NC60HD - STGB7NC60HD

N-CHANNEL 14A - 600V - TO-220/TO-220FP/D<sup>2</sup>PAK

Very Fast PowerMESH™ IGBT

勝特力材料 886-3-5753170  
勝特力電子(上海) 86-21-34970699  
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**Table 1: General Features**

| TYPE        | V <sub>CES</sub> | V <sub>CE(sat)</sub> (Max)<br>@25°C | I <sub>C</sub><br>@100°C |
|-------------|------------------|-------------------------------------|--------------------------|
| STGP7NC60HD | 600 V            | < 2.5 V                             | 14 A                     |
| STGF7NC60HD | 600 V            | < 2.5 V                             | 6 A                      |
| STGB7NC60HD | 600 V            | < 2.5 V                             | 14 A                     |

- LOWER ON-VOLTAGE DROP (V<sub>cesat</sub>)
- OFF LOSSES INCLUDE TAIL CURRENT
- LOSSES INCLUDE DIODE RECOVERY ENERGY
- LOWER C<sub>RES</sub>/C<sub>IES</sub> RATIO
- HIGH FREQUENCY OPERATION UP TO 70 KHz
- VERY SOFT ULTRA FAST RECOVERY ANTI PARALLEL DIODE
- NEW GENERATION PRODUCTS WITH TIGHTER PARAMETER DISTRIBUTION

## DESCRIPTION

Using the latest high voltage technology based on a patented strip layout, STMicroelectronics has designed an advanced family of IGBTs, the PowerMESH™ IGBTs, with outstanding performances. The suffix "H" identifies a family optimized for high frequency applications in order to achieve very high switching performances (reduced t<sub>fall</sub>) maintaining a low voltage drop.

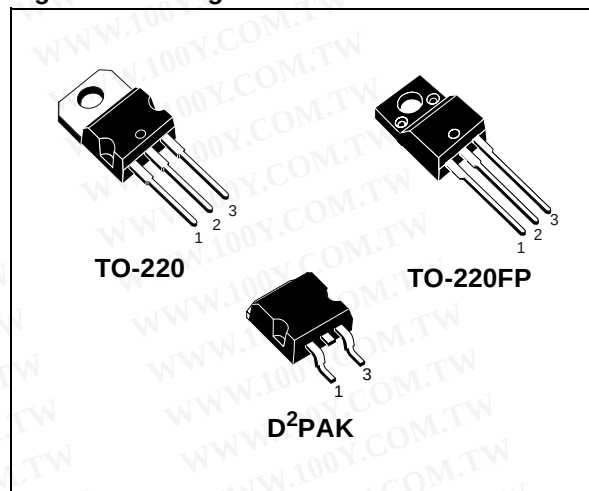
## APPLICATIONS

- HIGH FREQUENCY INVERTERS
- SMPS AND PFC IN BOTH HARD SWITCH AND RESONANT TOPOLOGIES
- MOTOR DRIVERS

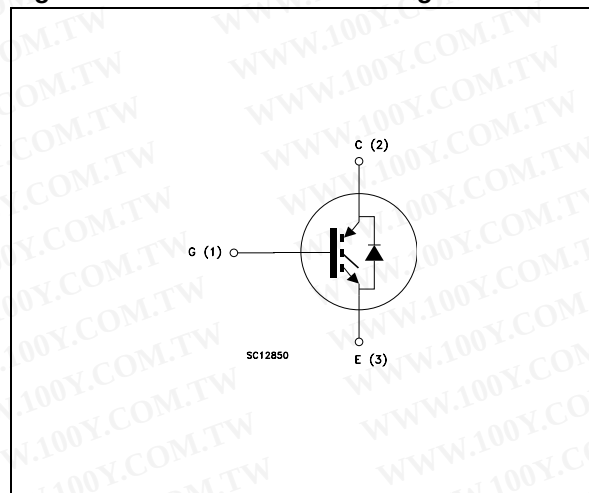
**Table 2: Order Code**

| PART NUMBER   | MARKING   | PACKAGE            | PACKAGING   |
|---------------|-----------|--------------------|-------------|
| STGP7NC60HD   | GP7NC60HD | TO-220             | TUBE        |
| STGF7NC60HD   | GF7NC60HD | TO-220FP           | TUBE        |
| STGB7NC60HDT4 | GB7NC60HD | D <sup>2</sup> PAK | TAPE & REEL |

**Figure 1: Package**



**Figure 2: Internal Schematic Diagram**



**Table 3: Absolute Maximum ratings**

| Symbol              | Parameter                                                           | Value                      |             | Unit |
|---------------------|---------------------------------------------------------------------|----------------------------|-------------|------|
|                     |                                                                     | STGP7NC60HD<br>STGB7NC60HD | STGF7NC60HD |      |
| V <sub>CES</sub>    | Collector-Emitter Voltage (V <sub>GS</sub> = 0)                     | 600                        |             | V    |
| V <sub>ECR</sub>    | Emitter-Collector Voltage                                           | 20                         |             | V    |
| V <sub>GE</sub>     | Gate-Emitter Voltage                                                | ±20                        |             | V    |
| I <sub>C</sub>      | Collector Current (continuous) at T <sub>C</sub> = 25°C (#)         | 25                         | 10          | A    |
| I <sub>C</sub>      | Collector Current (continuous) at T <sub>C</sub> = 100°C (#)        | 14                         | 6           | A    |
| I <sub>CM</sub> (□) | Collector Current (pulsed)                                          | 50                         |             | A    |
| I <sub>F</sub>      | Diode RMS Forward Current at T <sub>C</sub> = 25°C                  | 20                         |             | A    |
| P <sub>TOT</sub>    | Total Dissipation at T <sub>C</sub> = 25°C                          | 80                         | 25          | W    |
|                     | Derating Factor                                                     | 0.64                       | 0.20        | W/°C |
| V <sub>ISO</sub>    | Insulation Withstand Voltage A.C.(t = 1 sec; T <sub>c</sub> = 25°C) | --                         | 2500        | V    |
| T <sub>stg</sub>    | Storage Temperature                                                 | – 55 to 150                |             | °C   |
| T <sub>j</sub>      | Operating Junction Temperature                                      |                            |             |      |

(□) Pulse width limited by max. junction temperature.

**Table 4: Thermal Data**

|                       |                                                                                   |                              | Min. | Typ. | Max. |      |
|-----------------------|-----------------------------------------------------------------------------------|------------------------------|------|------|------|------|
| R <sub>thj-case</sub> | Thermal Resistance Junction-case                                                  | TO-220<br>D <sup>2</sup> PAK |      |      | 1.56 | °C/W |
|                       |                                                                                   | TO-220FP                     |      |      | 5.0  | °C/W |
| R <sub>thj-amb</sub>  | Thermal Resistance Junction-ambient                                               |                              |      |      | 62.5 | °C/W |
| T <sub>L</sub>        | Maximum Lead Temperature for Soldering Purpose<br>(1.6 mm from case, for 10 sec.) |                              |      | 300  |      | °C   |

**ELECTRICAL CHARACTERISTICS (T<sub>CASE</sub> = 25°C UNLESS OTHERWISE SPECIFIED)**
**Table 5: Main Parameters**

| Symbol               | Parameter                                          | Test Conditions                                                                                                    | Min. | Typ.        | Max.    | Unit     |
|----------------------|----------------------------------------------------|--------------------------------------------------------------------------------------------------------------------|------|-------------|---------|----------|
| V <sub>BR(CES)</sub> | Collector-Emitter Breakdown Voltage                | I <sub>C</sub> = 1 mA, V <sub>GE</sub> = 0                                                                         | 600  |             |         | V        |
| I <sub>CES</sub>     | Collector cut-off Current<br>(V <sub>GE</sub> = 0) | V <sub>CE</sub> = Max Rating, T <sub>C</sub> = 25 °C<br>V <sub>CE</sub> = Max Rating, T <sub>C</sub> = 125 °C      |      |             | 10<br>1 | μA<br>mA |
| I <sub>GES</sub>     | Gate-Emitter Leakage Current (V <sub>CE</sub> = 0) | V <sub>GE</sub> = ± 20V, V <sub>CE</sub> = 0                                                                       |      |             | ±100    | nA       |
| V <sub>GE(th)</sub>  | Gate Threshold Voltage                             | V <sub>CE</sub> = V <sub>GE</sub> , I <sub>C</sub> = 250 μA                                                        | 3.75 |             | 5.75    | V        |
| V <sub>CE(sat)</sub> | Collector-Emitter Saturation Voltage               | V <sub>GE</sub> = 15V, I <sub>C</sub> = 7 A<br>V <sub>GE</sub> = 15V, I <sub>C</sub> = 7 A, T <sub>c</sub> = 125°C |      | 1.85<br>1.7 | 2.5     | V<br>V   |

(#) Calculated according to the iterative formula:

$$I_C(T_C) = \frac{T_{JMAX} - T_C}{R_{THJ-C} \times V_{CESAT(MAX)}(T_C, I_C)}$$

## ELECTRICAL CHARACTERISTICS (CONTINUED)

Table 6: Dynamic

| Symbol                        | Parameter                                                         | Test Conditions                                                                                       | Min. | Typ.          | Max. | Unit           |
|-------------------------------|-------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------|------|---------------|------|----------------|
| $g_{fs}$ (1)                  | Forward Transconductance                                          | $V_{CE} = 15\text{ V}$ , $I_C = 7\text{ A}$                                                           |      | 4.30          |      | S              |
| $C_{ies}$                     | Input Capacitance                                                 | $V_{CE} = 25\text{ V}$ , $f = 1\text{ MHz}$ , $V_{GE} = 0$                                            |      | 720           |      | pF             |
| $C_{oes}$                     | Output Capacitance                                                |                                                                                                       |      | 81            |      | pF             |
| $C_{res}$                     | Reverse Transfer Capacitance                                      |                                                                                                       |      | 17            |      | pF             |
| $Q_g$<br>$Q_{ge}$<br>$Q_{gc}$ | Total Gate Charge<br>Gate-Emitter Charge<br>Gate-Collector Charge | $V_{CE} = 390\text{ V}$ , $I_C = 7\text{ A}$ ,<br>$V_{GE} = 15\text{ V}$<br>(see Figure 22)           |      | 35<br>7<br>16 | 48   | nC<br>nC<br>nC |
| $I_{CL}$                      | Turn-Off SOA Minimum Current                                      | $V_{clamp} = 480\text{ V}$ , $T_J = 150^\circ\text{C}$<br>$R_G = 10\ \Omega$ , $V_{GE} = 15\text{ V}$ | 50   |               |      | A              |

(1) Pulsed: Pulse duration= 300  $\mu\text{s}$ , duty cycle 1.5%

Table 7: Switching On

| Symbol                                 | Parameter                                                        | Test Conditions                                                                                                                            | Min. | Typ.                | Max. | Unit                         |
|----------------------------------------|------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------|------|---------------------|------|------------------------------|
| $t_{d(on)}$<br>$t_r$<br>$(di/dt)_{on}$ | Turn-on Delay Time<br>Current Rise Time<br>Turn-on Current Slope | $V_{CC} = 390\text{ V}$ , $I_C = 7\text{ A}$<br>$R_G = 10\ \Omega$ , $V_{GE} = 15\text{ V}$ , $T_J = 25^\circ\text{C}$<br>(see Figure 19)  |      | 18.5<br>8.5<br>1060 |      | ns<br>ns<br>A/ $\mu\text{s}$ |
| $t_{d(on)}$<br>$t_r$<br>$(di/dt)_{on}$ | Turn-on Delay Time<br>Current Rise Time<br>Turn-on Current Slope | $V_{CC} = 390\text{ V}$ , $I_C = 7\text{ A}$<br>$R_G = 10\ \Omega$ , $V_{GE} = 15\text{ V}$ , $T_J = 125^\circ\text{C}$<br>(see Figure 20) |      | 18.5<br>7<br>1000   |      | ns<br>ns<br>A/ $\mu\text{s}$ |

Table 8: Switching Off

| Symbol                                  | Parameter                                                         | Test Conditions                                                                                                                               | Min. | Typ.             | Max. | Unit           |
|-----------------------------------------|-------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------|------|------------------|------|----------------|
| $t_r(V_{off})$<br>$t_{d(off)}$<br>$t_f$ | Off Voltage Rise Time<br>Turn-off Delay Time<br>Current Fall Time | $V_{CC} = 390\text{ V}$ , $I_C = 7\text{ A}$ ,<br>$R_G = 10\ \Omega$ , $V_{GE} = 15\text{ V}$<br>$T_J = 25^\circ\text{C}$<br>(see Figure 20)  |      | 27<br>72<br>60   |      | ns<br>ns<br>ns |
| $t_r(V_{off})$<br>$t_{d(off)}$<br>$t_f$ | Off Voltage Rise Time<br>Turn-off Delay Time<br>Current Fall Time |                                                                                                                                               |      | 56<br>116<br>105 |      | ns<br>ns<br>ns |
| $t_r(V_{off})$<br>$t_{d(off)}$<br>$t_f$ | Off Voltage Rise Time<br>Turn-off Delay Time<br>Current Fall Time | $V_{CC} = 390\text{ V}$ , $I_C = 7\text{ A}$ ,<br>$R_G = 10\ \Omega$ , $V_{GE} = 15\text{ V}$<br>$T_J = 125^\circ\text{C}$<br>(see Figure 20) |      |                  |      |                |

Table 9: Switching Energy

| Symbol                                    | Parameter                                                                   | Test Conditions                                                                                                                            | Min. | Typ.              | Max.              | Unit                                            |
|-------------------------------------------|-----------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------|------|-------------------|-------------------|-------------------------------------------------|
| $E_{on}$ (2)<br>$E_{off}$ (3)<br>$E_{ts}$ | Turn-on Switching Losses<br>Turn-off Switching Loss<br>Total Switching Loss | $V_{CC} = 390\text{ V}$ , $I_C = 7\text{ A}$<br>$R_G = 10\ \Omega$ , $V_{GE} = 15\text{ V}$ , $T_J = 25^\circ\text{C}$<br>(see Figure 19)  |      | 95<br>115<br>210  | 125<br>150<br>275 | $\mu\text{J}$<br>$\mu\text{J}$<br>$\mu\text{J}$ |
| $E_{on}$ (2)<br>$E_{off}$ (3)<br>$E_{ts}$ | Turn-on Switching Losses<br>Turn-off Switching Loss<br>Total Switching Loss |                                                                                                                                            |      | 140<br>215<br>355 |                   | $\mu\text{J}$<br>$\mu\text{J}$<br>$\mu\text{J}$ |
| $E_{on}$ (2)<br>$E_{off}$ (3)<br>$E_{ts}$ | Turn-on Switching Losses<br>Turn-off Switching Loss<br>Total Switching Loss | $V_{CC} = 390\text{ V}$ , $I_C = 7\text{ A}$<br>$R_G = 10\ \Omega$ , $V_{GE} = 15\text{ V}$ , $T_J = 125^\circ\text{C}$<br>(see Figure 20) |      |                   |                   |                                                 |

(2)  $E_{on}$  is the turn-on losses when a typical diode is used in the test circuit in figure 2. If the IGBT is offered in a package with a co-pack diode, the co-pack diode is used as external diode. IGBTs & DIODE are at the same temperature ( $25^\circ\text{C}$  and  $125^\circ\text{C}$ )

(3) Turn-off losses include also the tail of the collector current.

Table 10: Collector-Emitter Diode

| Symbol                                            | Parameter                                                                                                        | Test Condition                                                                                           | Min. | Typ.                          | Max. | Unit                |
|---------------------------------------------------|------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------|------|-------------------------------|------|---------------------|
| $V_f$                                             | Forward On-Voltage                                                                                               | $I_f = 3.5 \text{ A}$<br>$I_f = 3.5 \text{ A}, T_j = 125^\circ\text{C}$                                  |      | 1.3<br>1.1                    | 1.9  | V<br>V              |
| $t_{rr}$<br>$t_a$<br>$Q_{rr}$<br>$I_{rrm}$<br>$S$ | Reverse Recovery Time<br><br>Reverse Recovery Charge<br>Reverse Recovery Current<br>Softness factor of the diode | $I_f = 7 \text{ A}, V_R = 40 \text{ V},$<br>$T_j = 25^\circ\text{C}, di/dt = 100 \text{ A}/\mu\text{s}$  |      | 37<br>22<br>40<br>2.1<br>0.68 |      | ns<br>ns<br>nC<br>A |
| $t_{rr}$<br>$t_a$<br>$Q_{rr}$<br>$I_{rrm}$<br>$S$ | Reverse Recovery Time<br><br>Reverse Recovery Charge<br>Reverse Recovery Current<br>Softness factor of the diode | $I_f = 7 \text{ A}, V_R = 40 \text{ V},$<br>$T_j = 125^\circ\text{C}, di/dt = 100 \text{ A}/\mu\text{s}$ |      | 61<br>34<br>98<br>3.2<br>0.79 |      | ns<br>ns<br>nC<br>A |

Figure 3: Output Characteristics

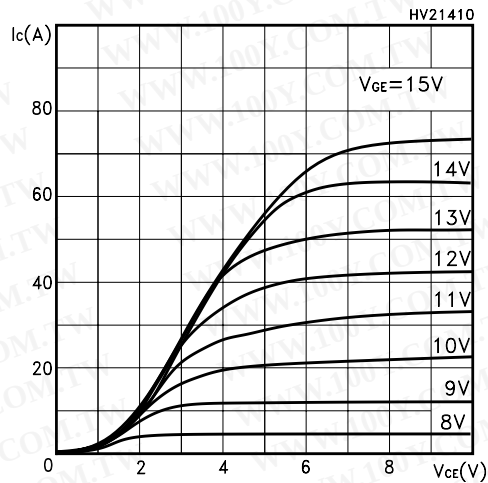


Figure 4: Transconductance

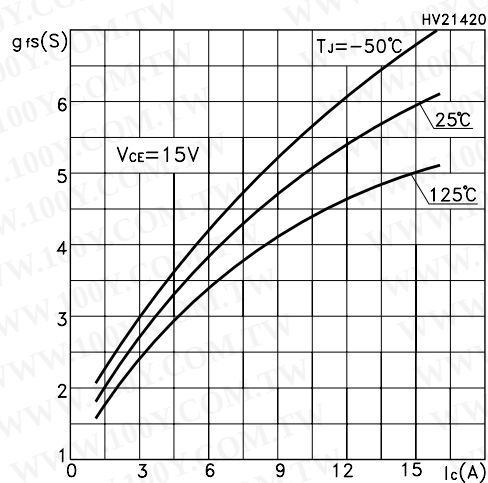


Figure 5: Collector-Emitter On Voltage vs Collector Current

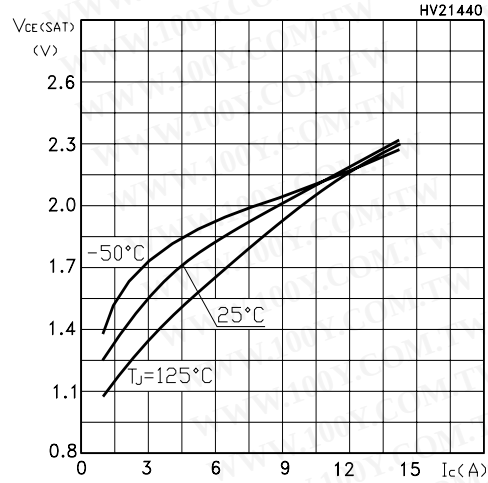


Figure 6: Transfer Characteristics

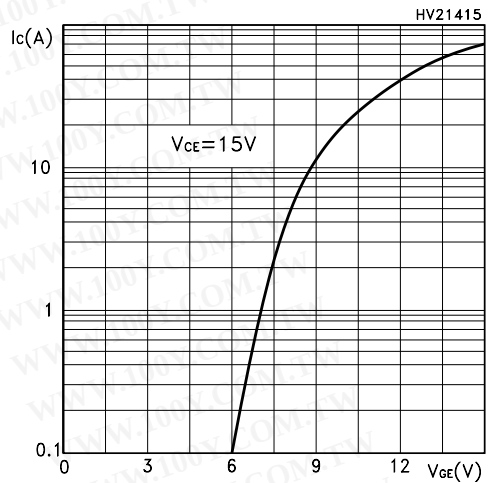


Figure 7: Collector-Emitter On Voltage vs Temperature

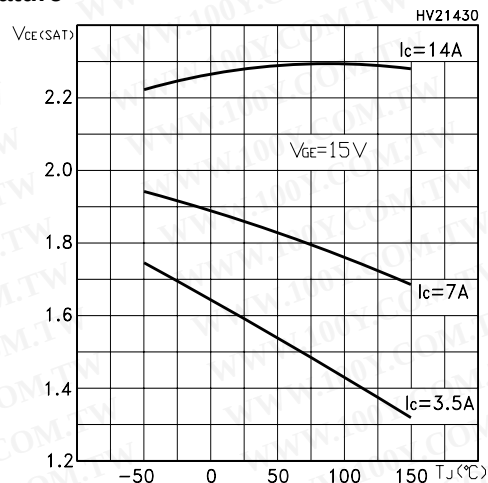
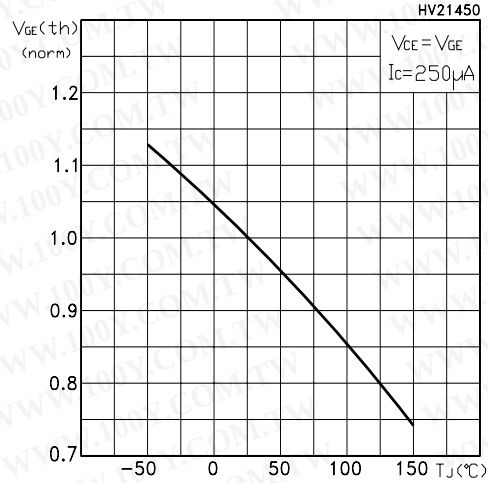
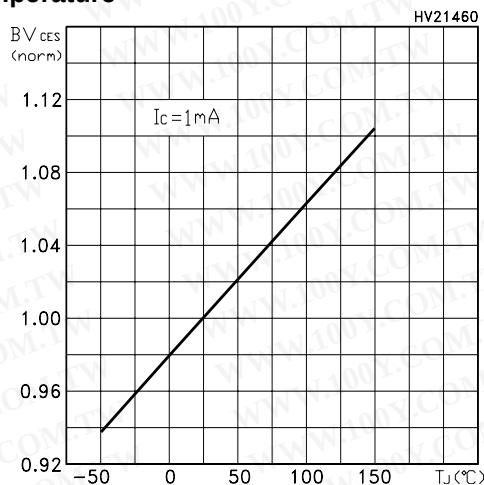


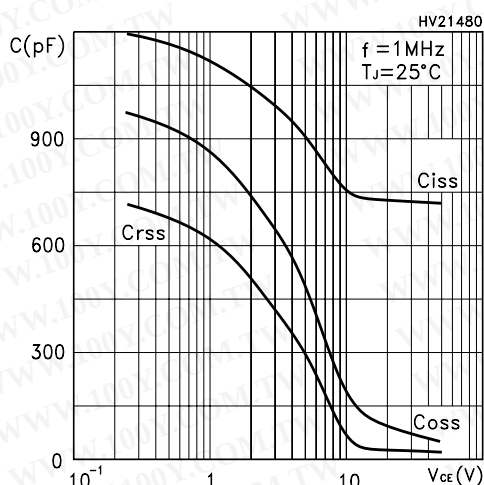
Figure 8: Normalized Gate Threshold vs Temperature



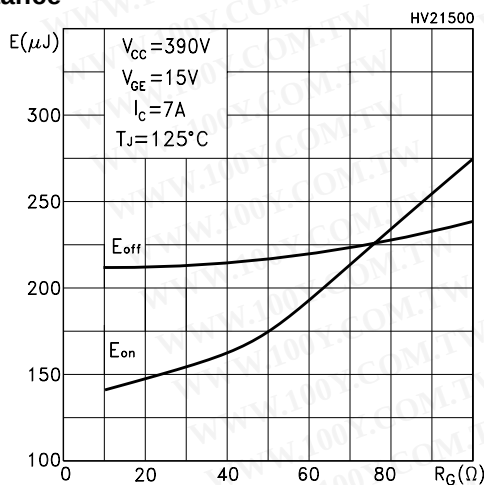
**Figure 9: Normalized Breakdown Voltage vs Temperature**



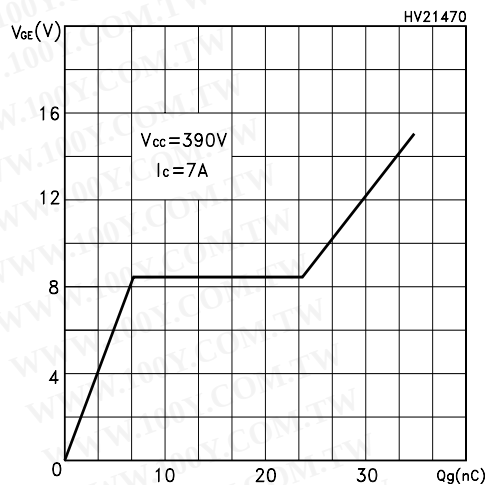
**Figure 10: Capacitance Variations**



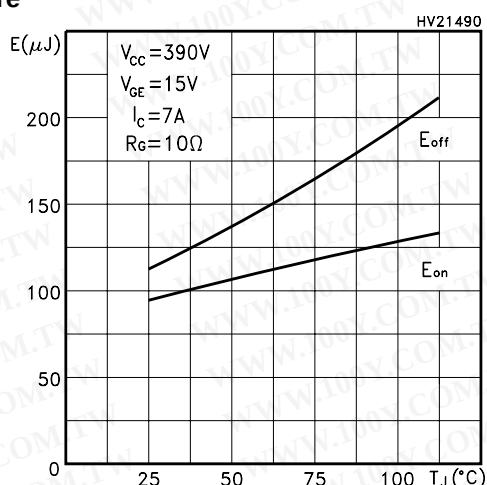
**Figure 11: Total Switching Losses vs Gate Resistance**



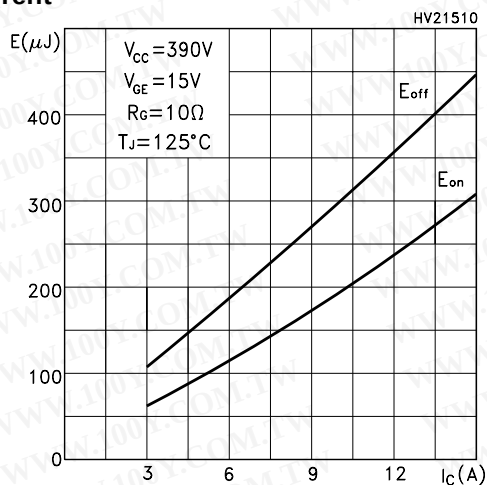
**Figure 12: Gate Charge vs Gate-Emitter Voltage**



**Figure 13: Total Switching Losses vs Temperature**



**Figure 14: Total Switching Losses vs Collector Current**



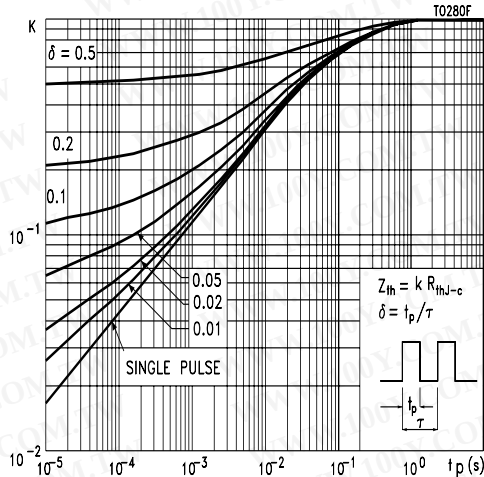
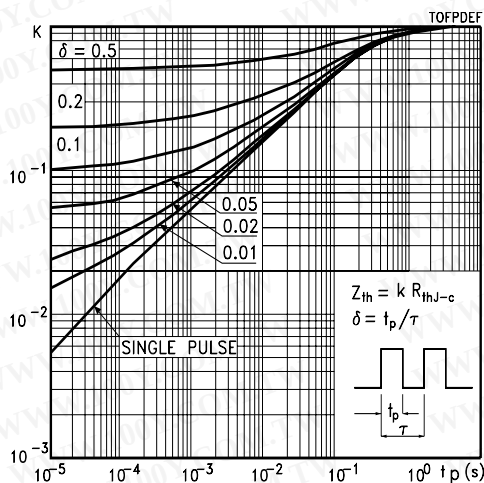
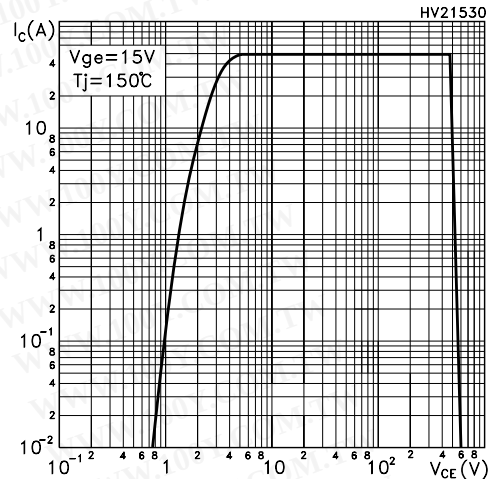
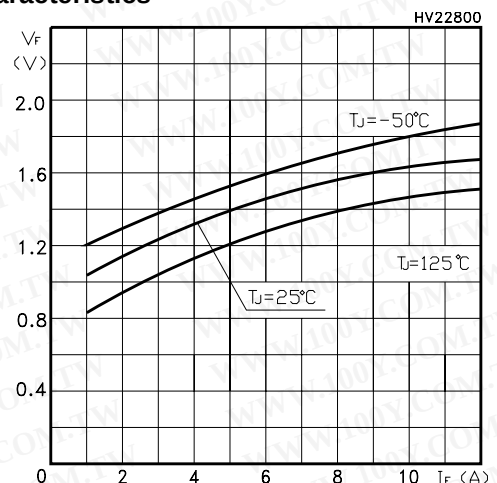
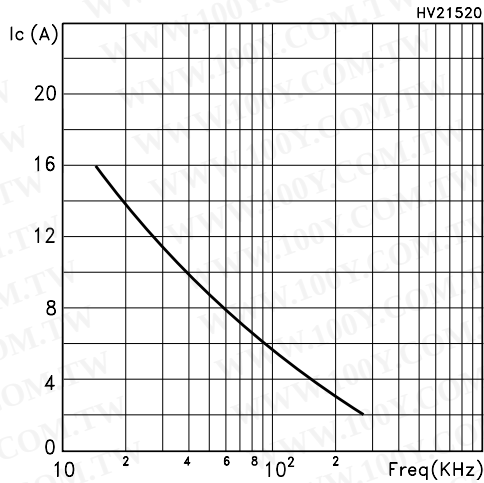
**Figure 15: Thermal Impedance For TO-220/D<sup>2</sup>PAK****Figure 16: Thermal Impedance For TO-220FP****Figure 17: Turn-Off SOA****Figure 18: Emitter-Collector Diode Characteristics**

Figure 19: Ic vs Frequency



For a fast IGBT suitable for high frequency applications, the typical collector current vs. maximum operating frequency curve is reported. That frequency is defined as follows:

$$f_{MAX} = (P_D - P_C) / (E_{ON} + E_{OFF})$$

1) The maximum power dissipation is limited by maximum junction to case thermal resistance:

$$P_D = \Delta T / R_{THJ-C}$$

considering  $\Delta T = T_J - T_C = 125^\circ C - 75^\circ C = 50^\circ C$

2) The conduction losses are:

$$P_C = I_C * V_{CE(SAT)} * \delta$$

with 50% of duty cycle,  $V_{CESAT}$  typical value @125°C.

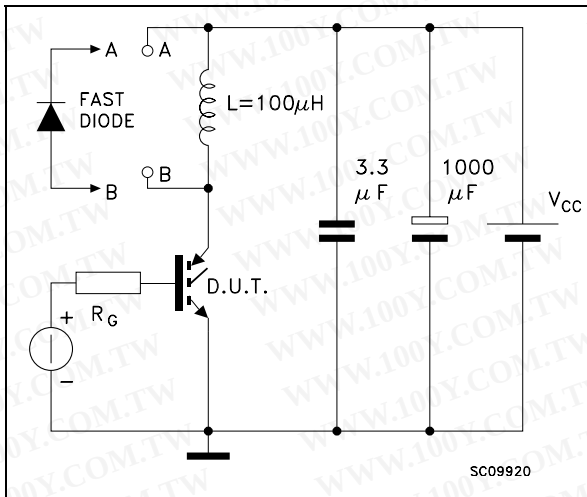
3) Power dissipation during ON & OFF commutations is due to the switching frequency:

$$P_{SW} = (E_{ON} + E_{OFF}) * \text{freq.}$$

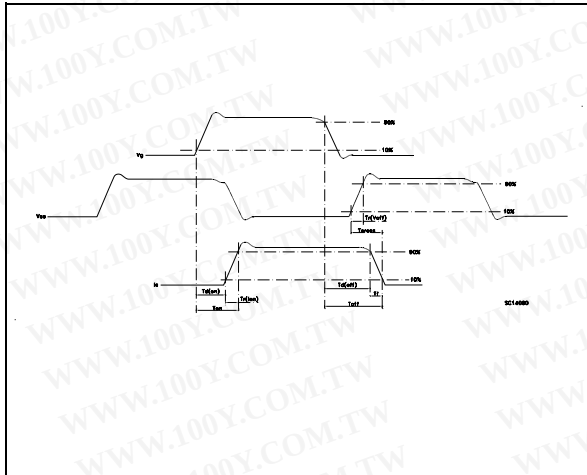
4) Typical values @ 125°C for switching losses are used (test conditions:  $V_{CE} = 390V$ ,  $V_{GE} = 15V$ ,  $R_G = 3.3 \text{ Ohm}$ ). Furthermore, diode recovery energy is included in the  $E_{ON}$  (see note 2), while the tail of the collector current is included in the  $E_{OFF}$  measurements (see note 3).



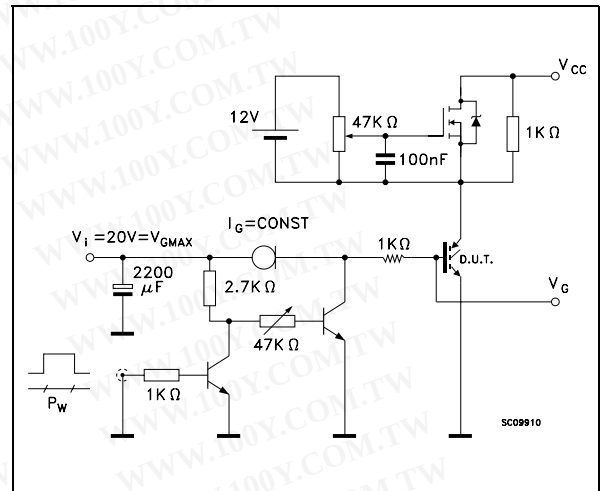
**Figure 20: Test Circuit for Inductive Load Switching**



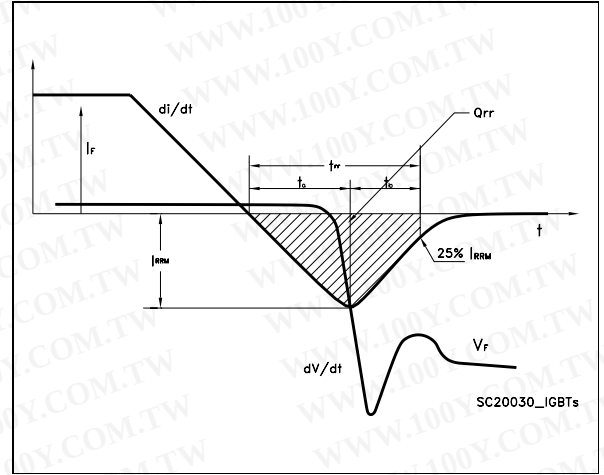
**Figure 21: Switching Waveforms**



**Figure 22: Gate Charge Test Circuit**

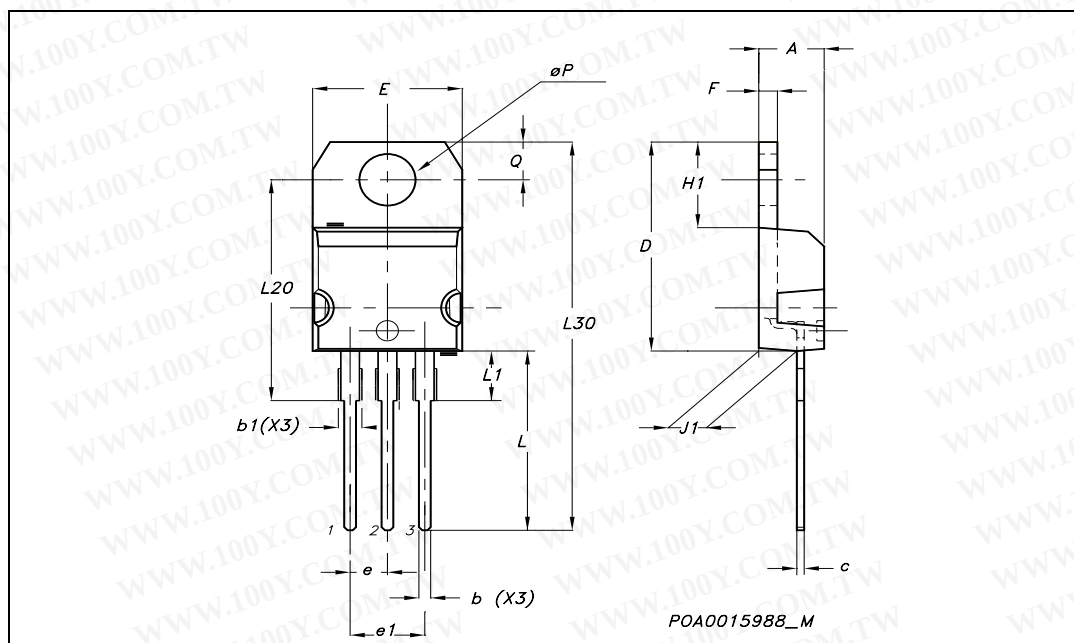


**Figure 23: Diode Recovery Time Waveforms**



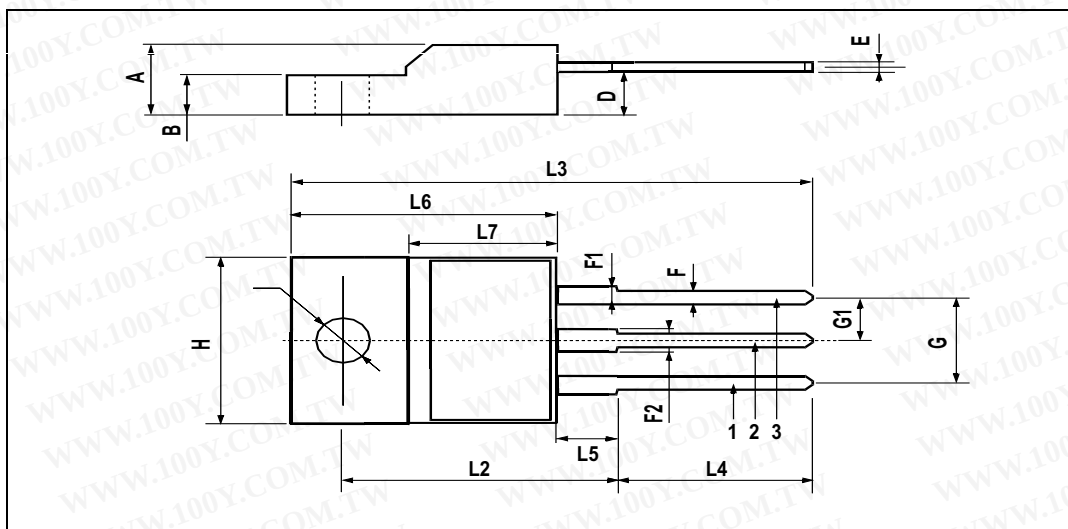
## TO-220 MECHANICAL DATA

| DIM. | mm.   |       |       | inch  |       |       |
|------|-------|-------|-------|-------|-------|-------|
|      | MIN.  | TYP   | MAX.  | MIN.  | TYP.  | MAX.  |
| A    | 4.40  |       | 4.60  | 0.173 |       | 0.181 |
| b    | 0.61  |       | 0.88  | 0.024 |       | 0.034 |
| b1   | 1.15  |       | 1.70  | 0.045 |       | 0.066 |
| c    | 0.49  |       | 0.70  | 0.019 |       | 0.027 |
| D    | 15.25 |       | 15.75 | 0.60  |       | 0.620 |
| E    | 10    |       | 10.40 | 0.393 |       | 0.409 |
| e    | 2.40  |       | 2.70  | 0.094 |       | 0.106 |
| e1   | 4.95  |       | 5.15  | 0.194 |       | 0.202 |
| F    | 1.23  |       | 1.32  | 0.048 |       | 0.052 |
| H1   | 6.20  |       | 6.60  | 0.244 |       | 0.256 |
| J1   | 2.40  |       | 2.72  | 0.094 |       | 0.107 |
| L    | 13    |       | 14    | 0.511 |       | 0.551 |
| L1   | 3.50  |       | 3.93  | 0.137 |       | 0.154 |
| L20  |       | 16.40 |       |       | 0.645 |       |
| L30  |       | 28.90 |       |       | 1.137 |       |
| øP   | 3.75  |       | 3.85  | 0.147 |       | 0.151 |
| Q    | 2.65  |       | 2.95  | 0.104 |       | 0.116 |



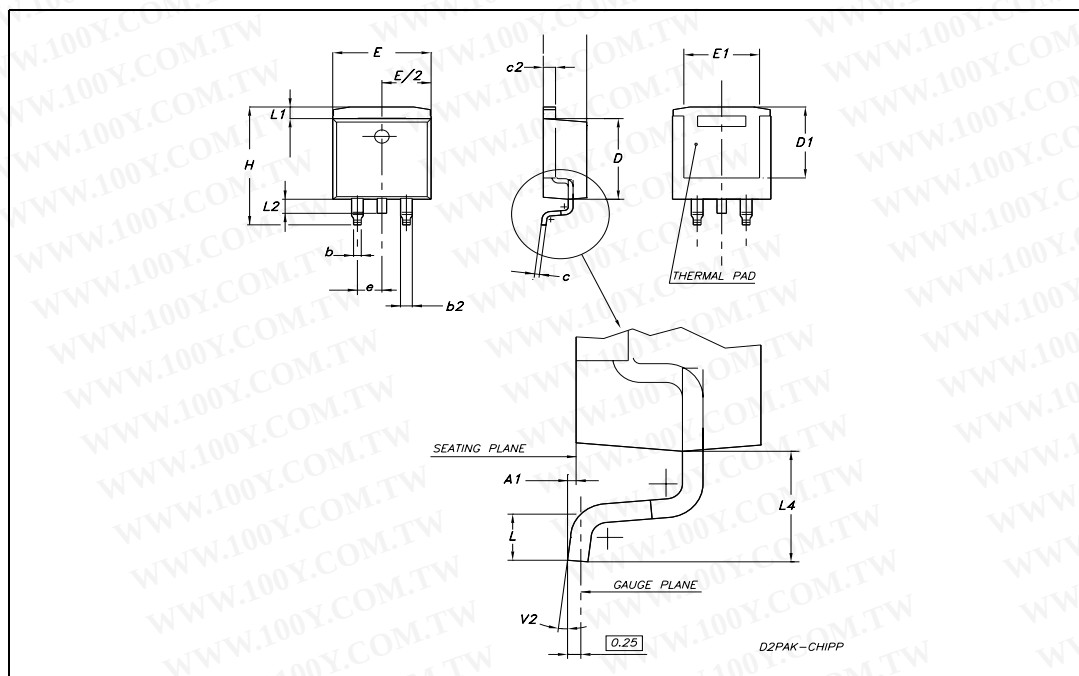
## TO-220FP MECHANICAL DATA

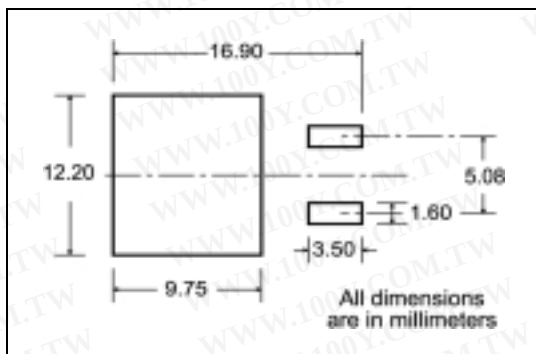
| DIM. | mm.  |     |      | inch  |       |       |
|------|------|-----|------|-------|-------|-------|
|      | MIN. | TYP | MAX. | MIN.  | TYP.  | MAX.  |
| A    | 4.4  |     | 4.6  | 0.173 |       | 0.181 |
| B    | 2.5  |     | 2.7  | 0.098 |       | 0.106 |
| D    | 2.5  |     | 2.75 | 0.098 |       | 0.108 |
| E    | 0.45 |     | 0.7  | 0.017 |       | 0.027 |
| F    | 0.75 |     | 1    | 0.030 |       | 0.039 |
| F1   | 1.15 |     | 1.7  | 0.045 |       | 0.067 |
| F2   | 1.15 |     | 1.7  | 0.045 |       | 0.067 |
| G    | 4.95 |     | 5.2  | 0.195 |       | 0.204 |
| G1   | 2.4  |     | 2.7  | 0.094 |       | 0.106 |
| H    | 10   |     | 10.4 | 0.393 |       | 0.409 |
| L2   |      | 16  |      |       | 0.630 |       |
| L3   | 28.6 |     | 30.6 | 1.126 |       | 1.204 |
| L4   | 9.8  |     | 10.6 | .0385 |       | 0.417 |
| L5   | 2.9  |     | 3.6  | 0.114 |       | 0.141 |
| L6   | 15.9 |     | 16.4 | 0.626 |       | 0.645 |
| L7   | 9    |     | 9.3  | 0.354 |       | 0.366 |
| Ø    | 3    |     | 3.2  | 0.118 |       | 0.126 |



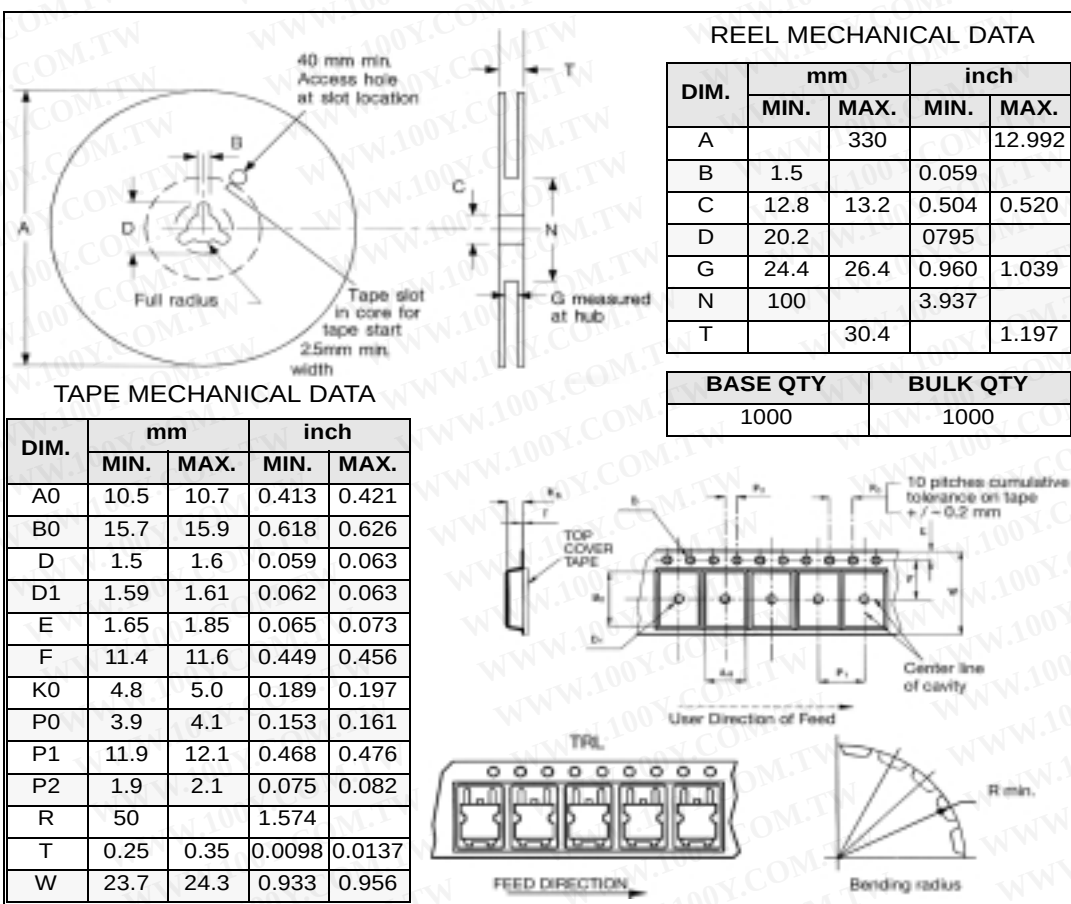
TO-263 (D<sup>2</sup>PAK) MECHANICAL DATA

| DIM. | mm.   |      |       | inch  |       |       |
|------|-------|------|-------|-------|-------|-------|
|      | MIN.  | TYP  | MAX.  | MIN.  | TYP.  | MAX.  |
| A    | 4.32  |      | 4.57  | 0.178 |       | 0.180 |
| A1   | 0.00  |      | 0.25  | 0.00  |       | 0.009 |
| b    | 0.71  |      | 0.91  | 0.028 |       | 0.350 |
| b2   | 1.15  |      | 1.40  | 0.045 |       | 0.055 |
| c    | 0.46  |      | 0.61  | 0.018 |       | 0.024 |
| c2   | 1.22  |      | 1.40  | 0.048 |       | 0.055 |
| D    | 8.89  | 9.02 | 9.40  | 0.350 | 0.355 | 0.370 |
| D1   | 8.01  |      |       | 0.315 |       |       |
| E    | 10.04 |      | 10.28 | 0.395 |       | 0.404 |
| e    |       | 2.54 |       |       | 0.010 |       |
| H    | 13.10 |      | 13.70 | 0.515 |       | 0.540 |
| L    | 1.30  |      | 1.70  | 0.051 |       | 0.067 |
| L1   | 1.15  |      | 1.39  | 0.045 |       | 0.054 |
| L2   | 1.27  |      | 1.77  | 0.050 |       | 0.069 |
| L4   | 2.70  |      | 3.10  | 0.106 |       | 0.122 |
| V2   | 0°    |      | 8°    | 0°    |       | 8°    |



D<sup>2</sup>PAK FOOTPRINT

## TAPE AND REEL SHIPMENT



\* on sales type

Table 11: Revision History 9

| Date        | Revision | Description of Changes               |
|-------------|----------|--------------------------------------|
| 07-Jun-2004 | 4        | Stylesheet update. No content change |
| 19-Aug-2004 | 5        | Complete Version                     |
| 17-Sep-2004 | 6        | Figure 18 has been added             |
| 09-Nov-2004 | 7        | Final datasheet                      |
| 19-Jan-2005 | 8        | Datasheet updated                    |
| 09-Jun-2005 | 9        | Modified title                       |

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